

# GL504 - DATA SHEET

### FEATURES

- designed to drive class D integrated receivers
- MPO range externally adjustable
- 150 µA typical current drain
- 46 dB of adjustable gain
- low external parts count

## STANDARD PACKAGING

- 8 Pin MICROpac
- 8 Pin PLID®
- 8 Pin SLT
- Chip (56 x 56 mils)

Au Bump

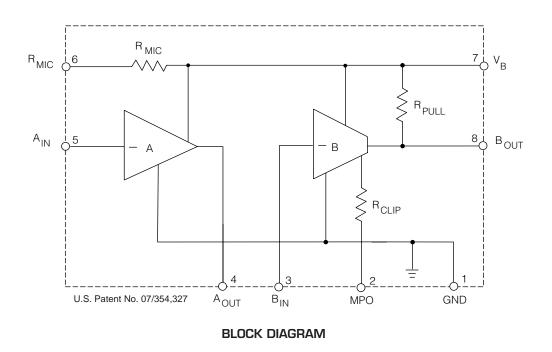
## DESCRIPTION

The GL504 is a low current preamplifier designed to drive the class D series of integrated receivers. This preamp has a built-in symmetrical peak clipping output limiter, 46 dB of adjustable gain, and requires few external components.

Composed of two stages, an inverting preamp with gain of 28 dB, and a transconductance block with gain of 18 dB, the GL504 is easily configured for mid-supply reference as required by the class D receivers.

The two stages of the GL504 must be AC coupled in order to maintain the DC bias conditions of each stage. Also, a 48 k $\Omega$  resistor, between the output and ground, is used to keep the receivers at mid-supply reference. The minimal total parts count, excluding an MPO variable resistor, requires 3 capacitors, a 100 k $\Omega$  volume control and the 48 k $\Omega$  bias resistor at the output.

The GL504 is capable of providing a flat frequency response with very little distortion.



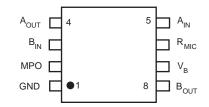
Revision Date: May 1998

Document No. 510 - 99 - 06

#### ABSOLUTE MAXIMUM RATINGS

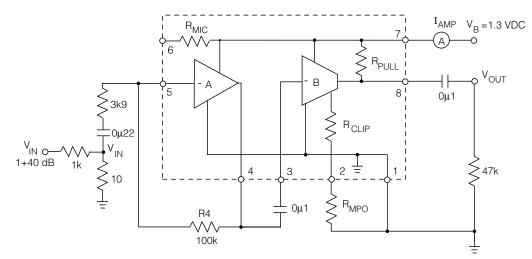
PARAMETER	VALUE / UNITS		
Supply Voltage	5 V		
Operating Temperature	-10°C to +40°C		
Storage Temperature	-20°C to +70°C		
CAUTION Class 1 ESD Sensitivity	R.		

# **PIN CONNECTION**



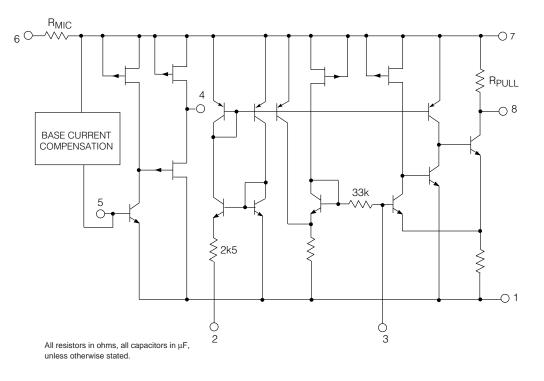
### **ELECTRICAL CHARACTERISTICS** (refer to test circuit) Supply Voltage = 1.3 V, Test Frequency 1kHz

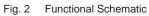
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Amplifier Current	I <sub>AMP</sub>	RMPO = 0	75	150	225	μΑ
Microphone Resistance	R <sub>MIC</sub>		3.0	4.0	5.3	kΩ
Input Referred Noise	IRN	NFB 0.2 to 10kHz at 12 dB/oct	-	2	-	μVRMS
Gain	A <sub>V</sub>	V <sub>IN</sub> = -80 dBV	44.5	46.5	48.5	dB
MPO Level	MPO	V <sub>IN</sub> = -50 dBV R <sub>MPO</sub> = 0	-16	-14	-12	dBV
Change in MPO	ΔΜΡΟ	$V_{_{\rm IN}}$ = -50 dBV R_{_{\rm MPO}} = 10 k $\Omega$	10	12	14	dB
Preamp A input Bias Current	I <sub>BIAS A</sub>		-25	0	+25	nA
Pull-up Resistance	R <sub>PULL</sub>		40	48	58	kΩ
Gain Loss	∆GAIN	R4 = 10 k, V <sub>IN</sub> = -70 dBV, RMP0 = 50 k	-	0	2.5	dB



All resistors in ohms, all capacitors in  $\mu\text{F},$  unless otherwise stated.

Fig. 1 Test Circuit





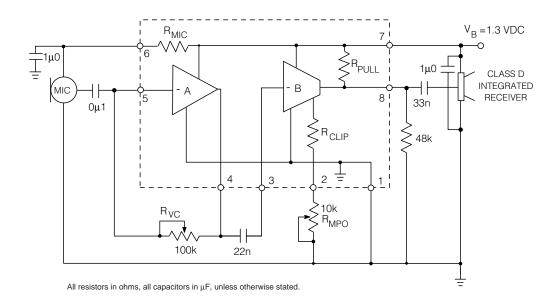
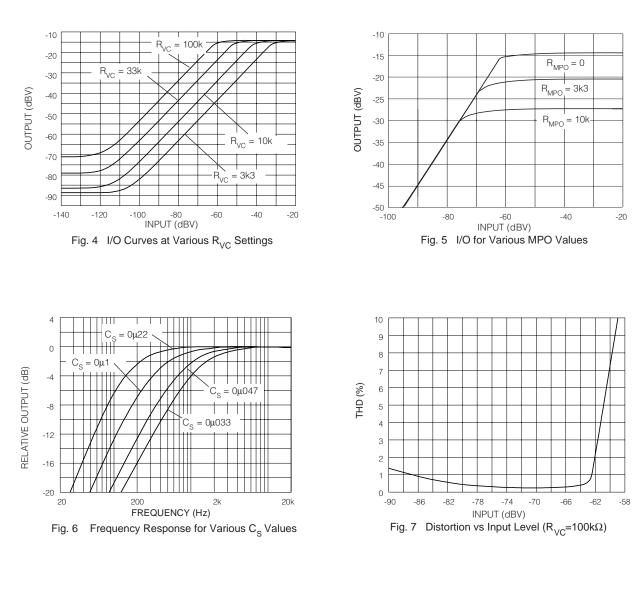


Fig. 3 Typical Application Circuit



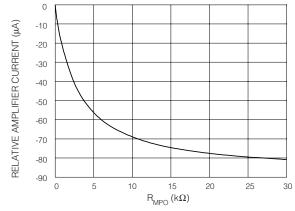
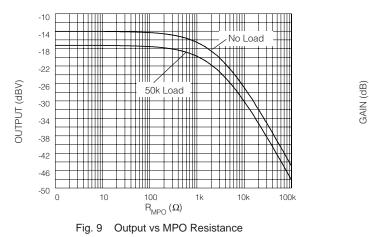
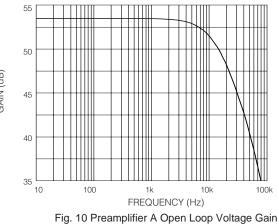


Fig. 8 Quiescent Current vs MPO Resistance





DOCUMENT IDENTIFICATION: DATA SHEET

The product is in production. Gennum reserves the right to make changes at any time to improve reliability, function or design, in order to provide the best product possible.

**REVISION NOTES:** 

Updated to Data sheet

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